

Single 4:1 Low r_{ON} Multiplexers

DESCRIPTION

The DG2034 is a low voltage, low r_{ON} , high bandwidth single 4 to 1 analog multiplexer designed for high performance switching of analog and video signals. Combining low power; fast switching; low on-resistance, flatness and matching; and small physical size, the DG2034 is ideal for portable and battery applications.

Built on Vishay Siliconix's low voltage CMOS process, the DG2034 has an epitaxial layer which prevents latchup. Break-before-make is guaranteed.

FEATURES

- Low voltage operation (1.8 V to 5.5 V)
- Low on-resistance - $r_{DS(on)}$: 4 Ω
- Off-isolation and crosstalk: - 55 dB at 10 MHz
- Fast switch - 25 ns t_{ON}
- Low charge injection - Q_{INJ} : 4.7 pC
- Low power consumption - 4 μ W


RoHS
COMPLIANT

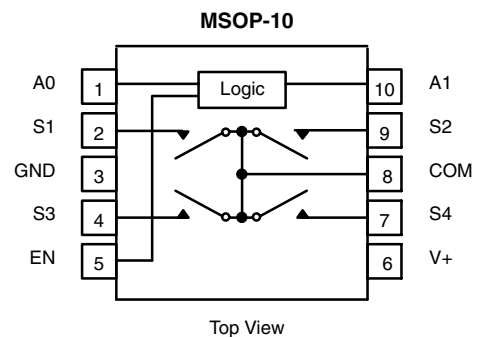
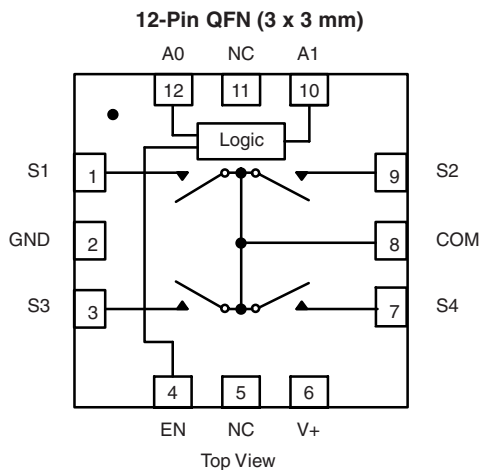
BENEFITS

- High accuracy
- High bandwidth
- TTL and low voltage logic compatibility
- Low power consumption
- Reduced PCB space

APPLICATIONS

- Mixed signal routing
- Portable and battery operated systems
- Low voltage data acquisition
- Modems
- PCMCIA cards

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

A1	A0	EN	ON Switch
X	X	0	None
0	0	1	S1
0	1	1	S2
1	0	1	S3
1	1	1	S4

ORDERING INFORMATION

Temp Range	Package	Part Number
- 40 °C to 85 °C	MSOP-10	DG2034DQ-T1-E3
	12-pin QFN (3 x 3 mm)	DG2034DN-T1-E4

ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit
Referenced V+ to GND	- 0.3 to + 6	V
A _X , E _N , S _X , COM ^a	- 0.3 to (V+ + 0.3)	
Continuous Current (Any Terminal)	± 50	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)	± 100	
Power Dissipation (Packags) ^b	QFN-12 (3 x 3 mm) ^c	mW
	MSOP-10 ^d	
Storage Temperature (D Suffix)	- 65 to 150	°C

Notes:

a. Signals on S_X, D_X, EN or A_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC Board.

c. Derate 16.2 mW/°C above 70 °C.

d. Derate 4.0 mW/°C above 70 °C.

SPECIFICATIONS (V+ = 3 V)

Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, V _{AL} = 0.4 V, V _{AH} = 1.5 V ^e	Temp. ^a	Limits - 40 to 85 °C			Unit
				Min. ^c	Typ. ^b	Max. ^c	
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}		Full	0		V+	V
On-Resistance	r _{ON}	V+ = 2.7 V, V _{COM} = 0.5 V/1.5 V/2.0 V I _S = 10 mA	Room Full		4	7 9	Ω
r _{ON} Match	Δr _{ON}		Room		0.1	0.3	
r _{ON} Flatness ^{d,f}	r _{ON} Flatness		Room		0.3	1.5	
Off Leakage Current ^g	I _{S(off)}	V+ = 3.3 V, V _S = 1 V/3 V V _{COM} = 3 V/1 V, V _{EN} = 0 V	Room Full	- 1 - 10	0.3	1 10	nA
COM Off Leakage Current ^g	I _{COM(off)}		Room Full	- 1 - 10	0.3	1 10	
Channel-On Leakage Current ^g	I _{COM(on)}	V+ = 3.3 V V _{COM} = V _S = 1 V/3 V	Room Full	- 1 - 10	0.3	1 10	
Digital Control							
Input Current ^d	I _A or I _{EN}	V _{A/EN} = 0 or V+, See Truth Table	Full	- 1.0		1.0	μA
Input High Voltage ^d	V _{AH} or V _{ENH}		Full	1.5			V
Input Low Voltage ^d	V _{AL} or V _{ENL}		Full			0.4	
Dynamic Characteristics							
Turn-On Time	t _{ON}	V _S = 1.5 V, R _L = 300 Ω	Room Full		25	35 45	ns
Turn-Off Time	t _{OFF}		Room Full		15	25 35	
Break-Before-Make Time ^d	t _D		Room		10.5		
Transition Time	t _{trans}	V _S = 1.5 V/0 V, V _S = 0 V/1.5 V, R _L = 300 Ω	Room Full		30	45 55	
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, V _{gen} = 0 V, R _{gen} = 0 Ω	Room		- 4.7		pC
Off-Isolation ^d	OIRR	R _L = 50 Ω, C _L = 5 pF	f = 1 MHz Room		- 73		dB
			f = 10 MHz Room		- 54		
Channel-to-Channel Crosstalk ^d	X _{TALK}	R _L = 50 Ω, C _L = 5 pF	f = 1 MHz Room		- 77		
			f = 10 MHz Room		- 59		
Off Capacitance ^d	C _{S(off)}	V+ = 2.7 V, f = 1 MHz	Room		14		pF
COM Off Capacitance ^d	C _{COM(off)}		Room		46		
COM On Capacitance ^d	C _{COM(on)}		Room		67		
Power Supply							
Power Supply Range	V+			2.7		3.3	V
Power Supply Current ^d	I+	V+ = 3.3 V, V _{A/EN} = 0 or 3.3 V, See Truth Table	Full			1.0	μA



SPECIFICATIONS (V+ = 5 V)								
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, V _{AL} = 0.8 V or V _{AH} = 2.4 V ^e		Temp. ^a	Limits - 40 to 85 °C			Unit
					Min. ^c	Typ. ^b	Max. ^c	
Analog Switch								
Analog Signal Range ^d	V _{ANALOG}	V+ = 4.5 V, V _{COM} = 1.5 V/2.5 V/3.5 V I _S = 10 mA		Full	0		V+	V
On-Resistance	r _{ON}			Room Full		3	5.5 7	Ω
r _{ON} Match	Δr _{ON}			Room		0.16	0.5	
r _{ON} Flatness ^{d,f}	r _{ON} Flatness			Room		0.6	1.5	
Off Leakage Current	I _{S(off)}	V+ = 5.5 V, V _S = 1 V/4.5 V V _{COM} = 4.5 V/1 V, V _{EN} = 0 V		Room Full	- 1 - 10	0.5	1 10	nA
COM Off Leakage Current	I _{COM(off)}			Room Full	- 1 - 10	0.5	1 10	
Channel-On Leakage Current	I _{COM(on)}	V+ = 5.5 V, V _{COM} = V _S = 1 V/4.5 V		Room Full	- 1 - 10	0.5	1 10	
Digital Control								
Input Current ^d	I _{AH} or I _{ENH}	V _A or V _{EN} = 0 or V+, See Truth Table		Full	- 1.0		1.0	μA
Input High Voltage ^d	V _{AH} or V _{ENH}			Full	2.4			V
Input Low Voltage ^d	V _{AL} or V _{ENL}			Full			0.8	
Dynamic Characteristics								
Turn-On Time	t _{ON}	V _S = 3.0 V, R _L = 300 Ω		Room Full		18	30 40	ns
Turn-Off Time	t _{OFF}			Room Full		12	20 30	
Break-Before-Make Time ^d	t _D			Room		10.5		
Transition Time	t _{trans}	V _S = 3 V/0 V, V _S = 0 V/3 V, R _L = 300 Ω		Room Full		25	40 50	
Off-Isolation ^d	OIRR	R _L = 50 Ω, C _L = 5 p	f = 1 MHz	Room		- 73		dB
			f = 10 MHz	Room		- 53.5		
Channel-to-Channel Crosstalk ^d	X _{TALK}	R _L = 50 Ω, C _L = 5 pF	f = 1 MHz	Room		- 77		
			f = 10 MHz	Room		- 60.2		
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, V _{gen} = 0 V, R _{gen} = 0 Ω		Room		- 4.4		pC
Off Capacitance ^d	C _{S(off)}	V+ = 5 V, f = 1 MHz		Room		13		pF
COM Off Capacitance ^d	C _{COM(off)}			Room		43		
COM On Capacitance ^d	C _{COM(on)}			Room		64		
Power Supply								
Power Supply Range	V+				4.5		5.5	V
Power Supply Current	I+	V+ = 5.5 V, V _{A/EN} = 0 or 5.5 V, See Truth Table		Full			1.0	μA

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

d. Guarantee by design, not subjected to production test.

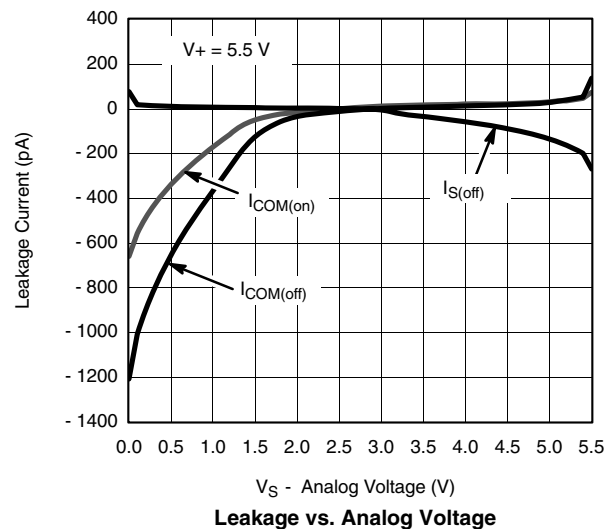
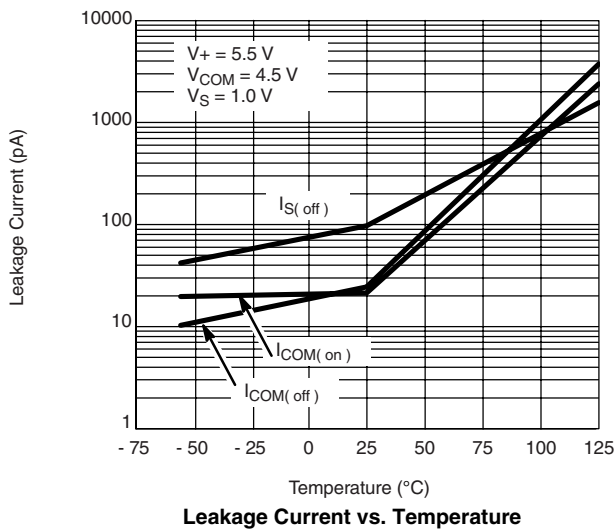
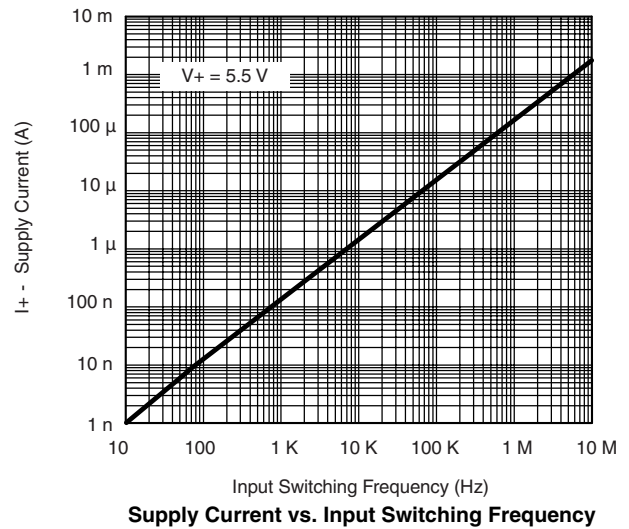
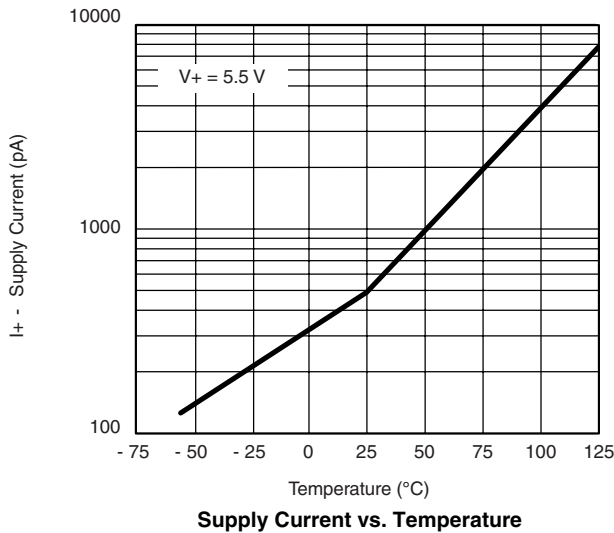
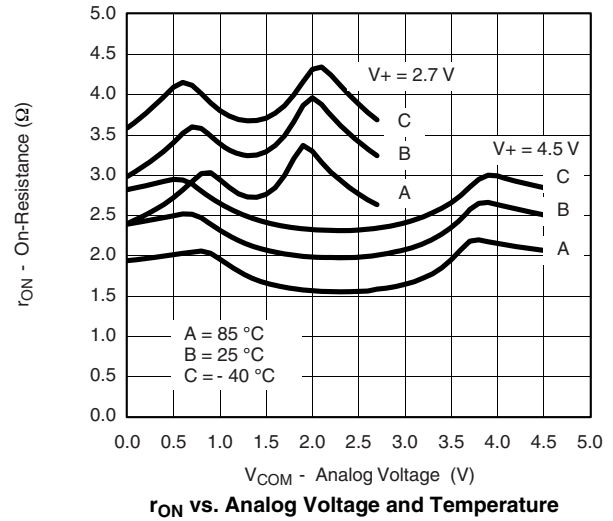
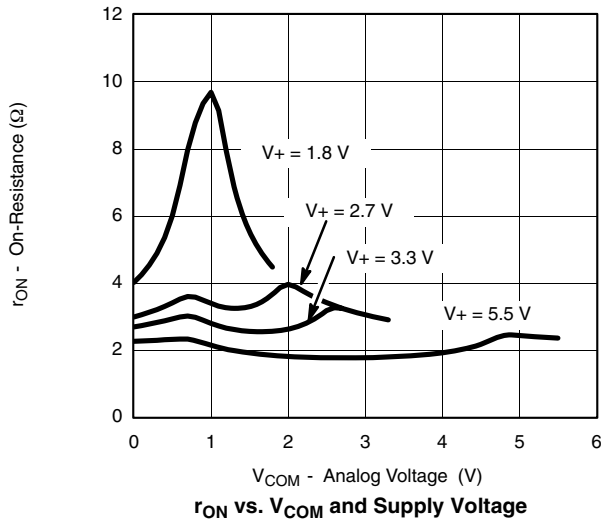
e. V_A, E_N = input voltage to perform proper function.

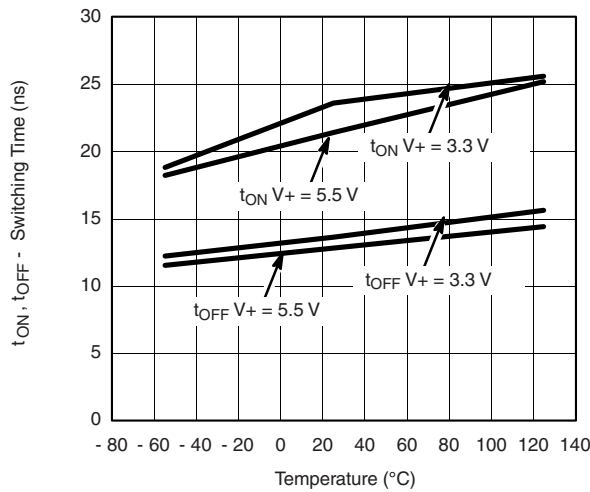
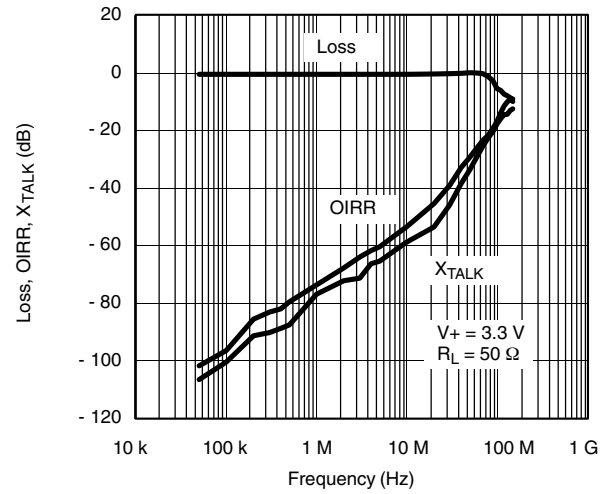
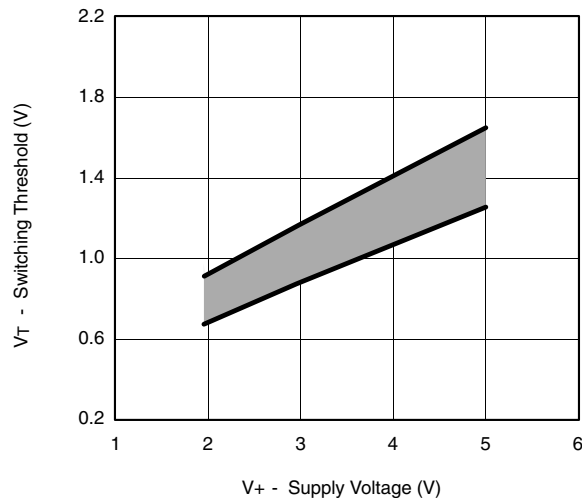
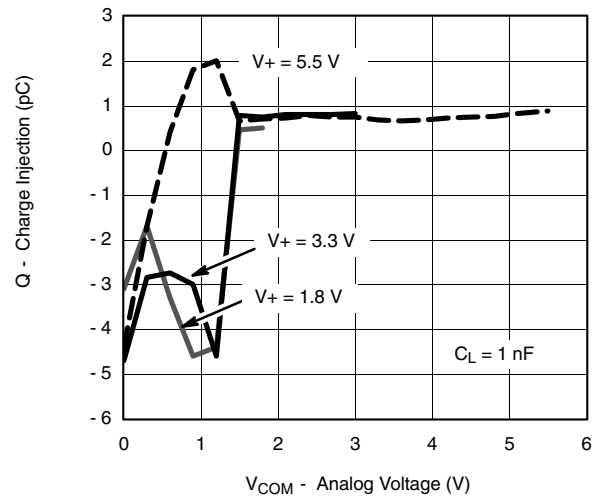
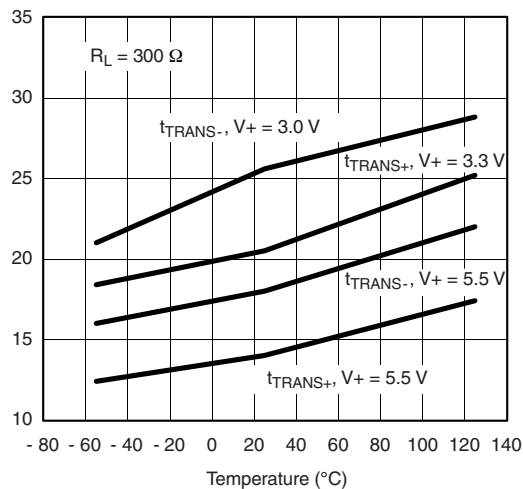
f. Difference of min and max values.

g. Guaranteed by 5 V testing.

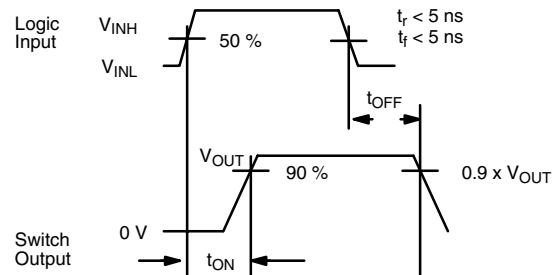
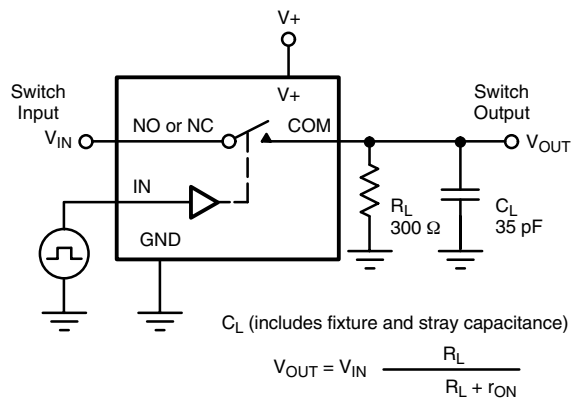
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Switching Time vs. Temperature

Insertion Loss, Off-Isolation Crosstalk vs. Frequency

Switching Threshold vs. Supply Voltage

Charge Injection vs. Analog Voltage

Transition Time vs. Temperature

TEST CIRCUITS



Note: Logic input waveform is inverted for switches that have the opposite logic sense control

Figure 1. Switching Time

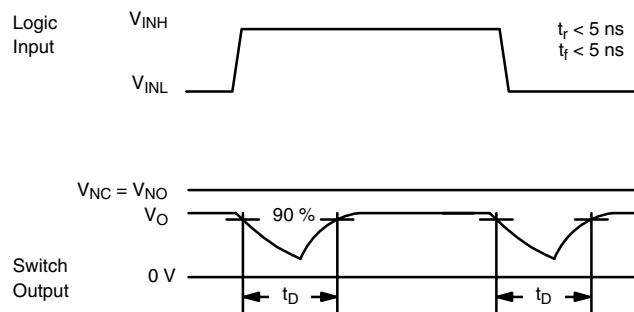
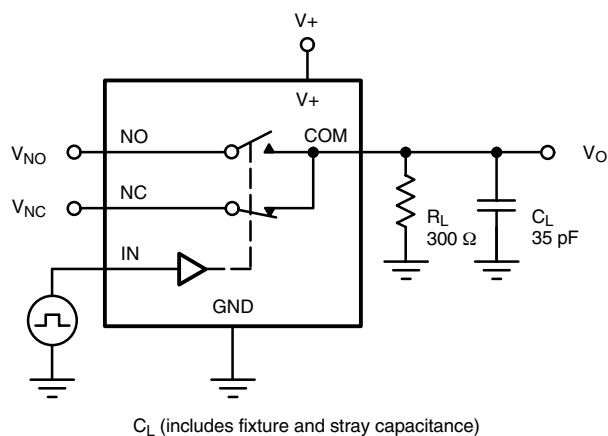


Figure 2. Break-Before-Make

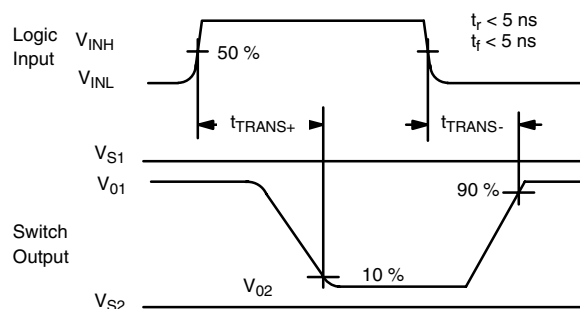
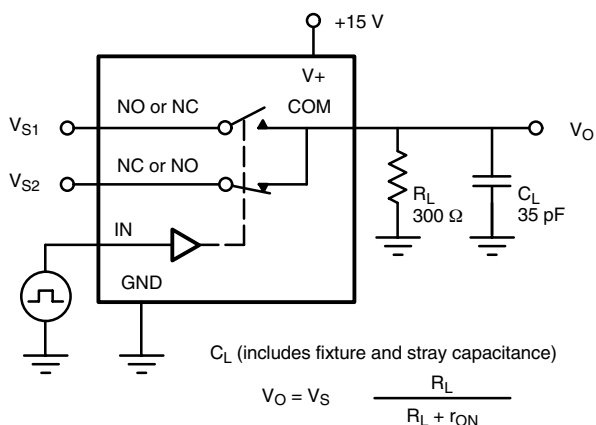
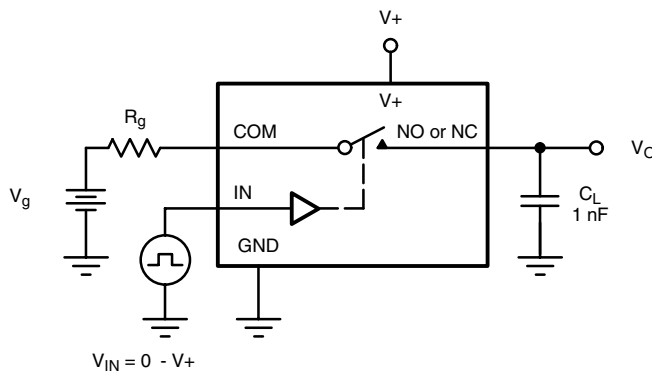
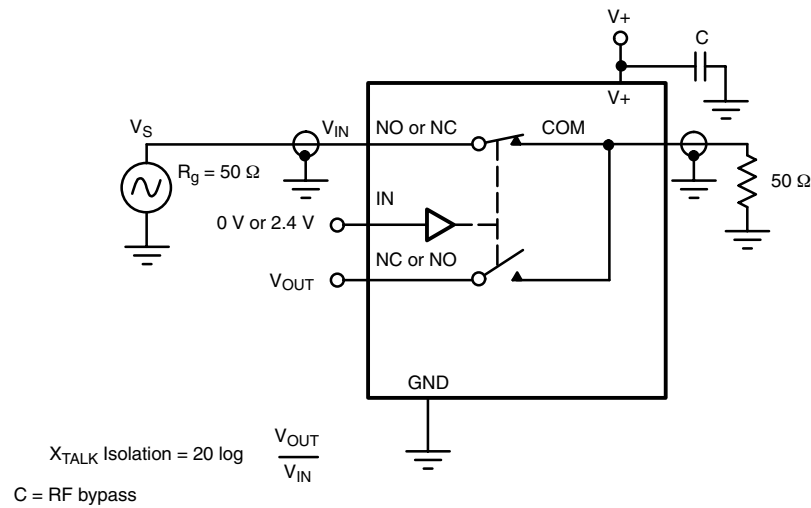
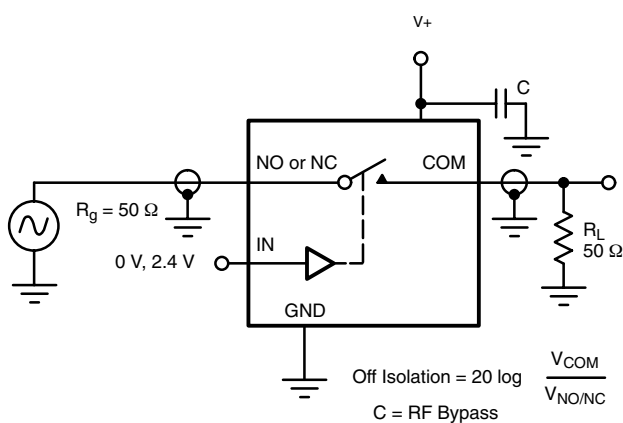
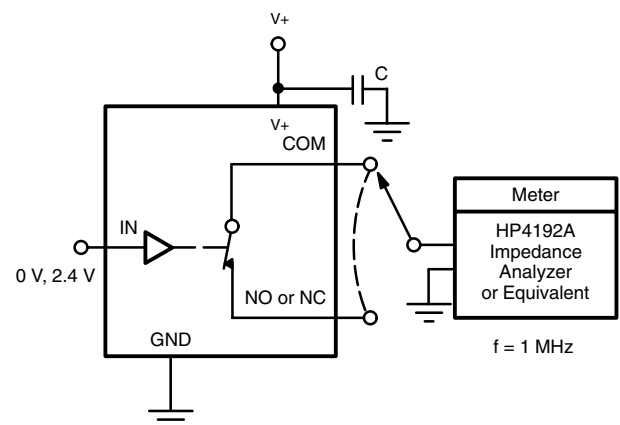


Figure 3. Transition Time

TEST CIRCUITS

Figure 4. Charge Injection

Figure 5. Crosstalk

Figure 6. Off Isolation

Figure 7. Source/Drain Capacitances

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